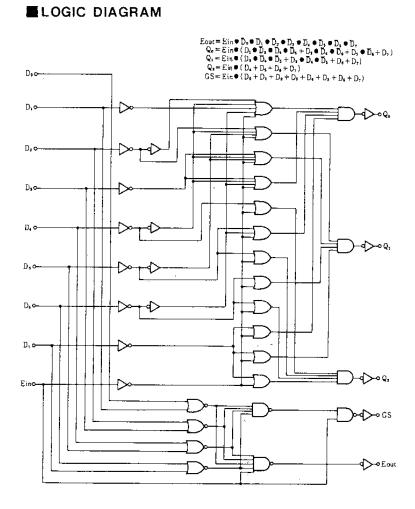
HD14532B

8-bit Priority Encoder

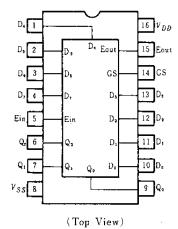
The HD14532B priority encoder is to provide a binary address for the active input with the highest priority. Eight data inputs (D0 thru D7) and an enable input (Ein) are provided. Five outputs are available, three are address outputs (Q0 thru Q2), one group select (GS) and one enable output (Eout).

FEATURES

- Quiescent Current = 5nA/pkg typ. @5V
- Noise Immunity = 45% of V_{DD} typ.
- Low Input Capacitance = 5pF typ.
- Supply Voltage Range = 3 to 18V
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range



PIN ARRANGEMENT



TRUTH TABLE

Inputs										Outputs					
E_{in}	\mathbf{D}_{7}	D	D ₅	D.	D₃	Dz	D	Do	GS	Q	Q	Q	E		
0	×	×	×	×	×	×	×	×	0	0	0	0	0		
1	0	0	0	0	0	0	0	0	0	0	0	0	1		
1	1	×	×	×	×	×	×	×	1	1	1	1	0		
1	0	1	×	×	×	×	×	×	1	1	1	0	0		
1	0	0	1	×	×	×	×	×	1	1	0	1	0		
1	0	0	0	1	×	×	×	×	1	1	0	0	0		
1	0	0	0	0	1	×	×	×	1	0	1	1	0		
1	0	0	0	0	0	1	×	×	1	0	1	0	0		
1	0	0	0	0	0	0	1	×	1	0	0	1	0		
1	0	0	0	0	0	0	0	1	1	0	0	0	0		

× = Don't Care

Characteristic	Symbol		T o be	40°C		25°C			85°C		TT -4	
Characteristic	Symbol	$V_{pp}(V)$ Test Conditions		min	max	min	typ	max	min	max	Unit	
		5.0		-	0.05	_	0	0.05	-	0.05	ν	
	Vol	10	$V_{in} = V_{DD}$ or 0		0.05	_	0	0.05		0.05		
Output Voltage		15		_	0.05	_	0	0.05	_	0.05		
Output Voltage	-	5.0	$V_{in} = 0$ or V_{DD}	4.95		4.95	5.0		4.95	-	v	
	V _{aH}	10		9.95		9.95	10	-	9.95	-		
		15		14.95		14.95	15	_	14.95	-		
· · · · · · · · · · · · · · · · · · ·		5.0	$V_{oxt} = 4.5 \text{ or } 0.5 \text{V}$		1.5		2.25	1.5	—	1.5		
	VIL	10	V _{out} =9.0 or 1.0V	-	3.0		4.50	3.0	—	3.0	V	
Input Voltage		15	$V_{out} = 13.5 \text{ or } 1.5 \text{V}$		4.0	_	6.75	4.0	—	4.0		
Input voltage		5.0	$V_{axt} = 0.5 \text{ or } 4.5 \text{V}$	3.5		3.5	2.75	—	3.5	_	v	
	V _{IH}	10	$V_{yxl} = 1.0 \text{ or } 9.0 \text{V}$	7.0	-	7.0	5.50	—	7.0	_		
	1	15	$V_{out} = 1.5 \text{ or } 13.5 \text{V}$	11.0	_	11.0	8.25	_	11.0	_		
		5.0	$V_{OH} = 2.5 \text{V}$	-1.0		-0.8	-1.7	_	-0.6	—	mA	
		5.0	$V_{OH} = 4.6 \mathrm{V}$	-0.2	-	-0.16	-0.36	_	-0.12	_		
	Іон	10	$V_{OH} = 9.5 V$	-0.5		-0.4	-0.9	_	-0.3	—		
Output Drive Current		15	$V_{QH} = 13.5 V$	-1.4		-1.2	-3.5	—	-1.0			
		5.0	$V_{0L} = 0.4$ V	0.52	-	0.44	0.88		0.36		mA	
	IOL	10	$V_{ol} = 0.5 V$	1.3		1.1	2.25		0.9	_		
		15	$V_{oL} = 1.5 V$	3.6	_	3.0	8.8		2.4			
Input Current	I.n.	15			±0.3	—	±0.00001	± 0.3	_	±1.0	μA	
Input Capacitance	C.,		$V_{in} = 0$	-			5.0	7.5		<u> </u>	pF	
····		5.0	7 0 1	- 1	20		0.005	20		150	-	
Quiescent Current	IDD	10	Zero Signal, per Package	_	40	T –	0.010	40	-	300		
		15		_	80	-	0.015	80	_	600		
		5.0	Dynamic $\div I_{DD}$,				1.74	-	_	-		
Total Supply Current*	Ιτ	10	per Gate	-	-	- 1	3.65		-		μA	
		15	$C_L = 50 \text{pF}, f = 1 \text{kHz}$	_		_	5.73	_	-		1	

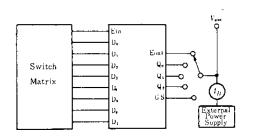
ELECTRICAL CHARACTERISTICS

* To calculate total supply current at frequency other than 1kHz.

 $(\textcircled{V}_{00} - 5.0 V I_T - (1.74 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 10 V I_T - (3.65 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 15 V I_T - (5.73 \mu A/kHz)f + I_{00}, (\textcircled{O} V_{00} - 1$

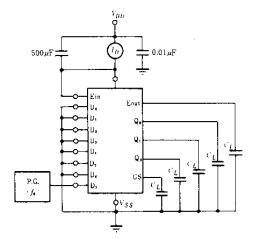
DC CHARACTERISTIC TEST CIRCUIT

• Iон, Iol



Output	Iol		Іон					
Under	$V_{GS} = V_{DD}, \ V_D$	s = V _{mt}	$V_{GS} = -V_{DD}, V_{DS} = V_{out} - V_{DD}$					
Test	$D_0 \sim D_7$	Ein	$D_0 \sim D_6$	D ₇	Ein			
Enst	×	0	0	0	1			
Q,	×	0	0	1	1			
Qı	×	0	0	1	1			
Qz	×	0	0	1	1			
GS	×	0	0	1	1			

Typical Power Dissipation



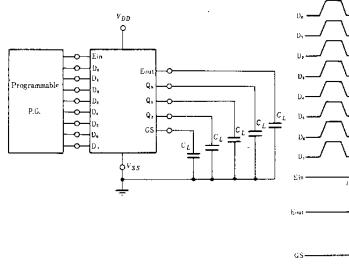


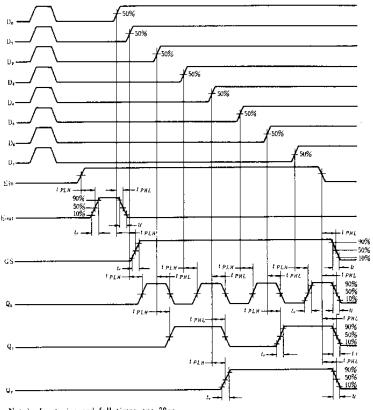
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Characteri	Symbol	$V_{DD}(\mathbf{V})$	min	typ	max	Unit	
	t,	5.0		180	400	ns.	
Output Rise Time		10	_	90	200		
			15		65	160	
		5.0	_	100	200		
Output Fall Time		t,	10	_	50	100	ns
			15	_	37	80	
			5.0	—	205	475	ns
· •	Ein to Eout		10	_	110	250	
			15		80	190	
	Ein to GS		5.0		175	400	
			10	_	90	200	
			15		65	155	
	· · · · · · · · · · · · · · · · · · ·	tplh, tphL	5.0	_	280	650	
Propagation Delay Time	Ein to Qn		10		140	325	
			15	—	100	250	
			5.0		300	720	
	Dn to Qn		10	-	170	350	
			15	—	110	265	
	_		5.0		280	650	
	Dn to GS		10		140	325	
			15		100	250	

SWITCHING CHARACTERISTICS ($C_L = 50 \text{ pF}, Ta = 25^{\circ}\text{C}$)

SWITCHING TIME TEST CIRCUIT

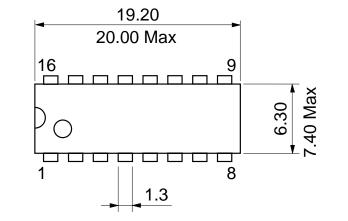




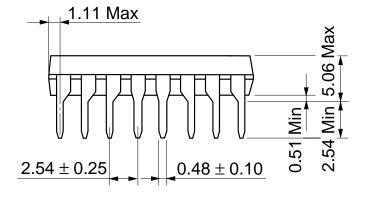
Note) Input rise and fall times are 20ns

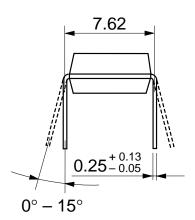


Unit: mm





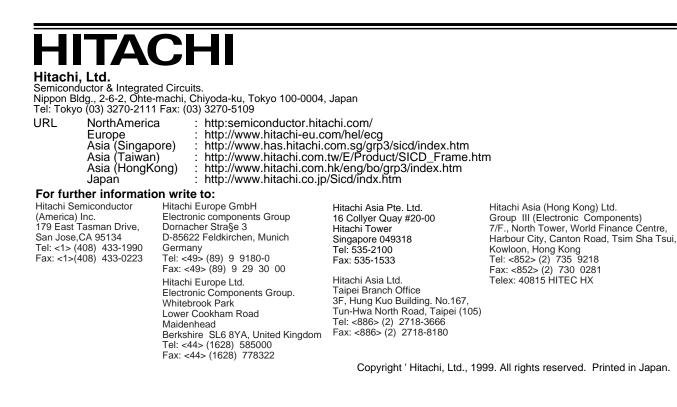




Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

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